DC Input, High Voltage Photo Darlington Transistor Coupler

Description

The SLM352 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar high voltage darlington phototransistor detector in a plastic SOP4 package.

With the robust coplanar double mold structure, SLM352 series provide the most stable isolation feature.

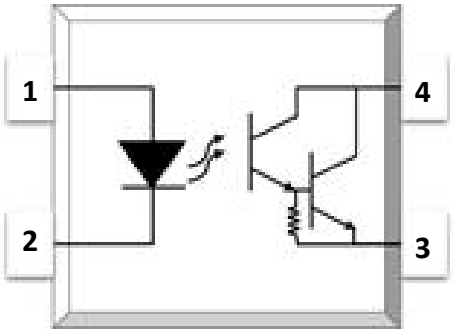
Features

- High isolation 3750 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- Operating temperature range - 55 °C to 100 °C
- REACH compliance
- Halogen free
- MSL class 1
- Regulatory Approvals
  - UL - UL1577
  - VDE - EN60747-5-5(VDE0884-5)
  - CQC - GB4943.1, GB8898
  - cUL- CSA Component Acceptance Service Notice No. 5A

Applications

- Sequence controller
- Telephone/FAX
- System appliances, measuring instrument
- Programmable logic controller

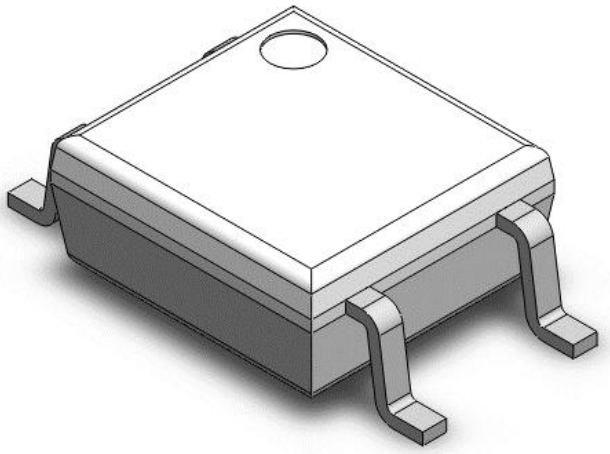
SCHEMATIC



PIN DEFINITION

1. Anode
2. Cathode
3. Emitter
4. Collector

PACKAGE OUTLINE



ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	VALUE	UNIT	NOTE
INPUT				
Forward Current	I_F	60	mA	
Peak Forward Current	I_{FP}	1	A	1
Reverse Voltage	V_R	6	V	
Input Power Dissipation	P_I	100	mW	
OUTPUT				
Collector - Emitter Voltage	V_{CEO}	350	V	
Emitter - Collector Voltage	V_{ECO}	0.1	V	
Collector Current	I_C	150	mA	
Output Power Dissipation	P_O	150	mW	
COMMON				
Total Power Dissipation	Ptot	200	mW	
Isolation Voltage	Viso	3750	Vrms	2
Operating Temperature	Topr	-55~110	°C	
Storage Temperature	Tstg	-55~125	°C	
Soldering Temperature	Tsol	260	°C	

Note 1. 100μs pulse, 100Hz frequency

Note 2. AC For 1 Minute, R.H. = 40 ~ 60%

ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C							
PARAMETER	SYMBOL	MIN	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
INPUT							
Forward Voltage	V_F	-	1.24	1.4	V	IF=10mA	
Reverse Current	I_R	-	-	10	μA	VR=6V	
Input Capacitance	Cin	-	10	-	pF	V=0, f=1kHz	
OUTPUT							
Collector Dark Current	I_{CEO}	-	-	200	nA	VCE=200V, IF=0	
Collector-Emitter Breakdown Voltage	BV_{CEO}	350	-	-	V	IC=0.1mA, IF=0	
Emitter-Collector Breakdown Voltage	BV_{ECO}	0.1	-	-	V	IE=0.1mA, IF=0	
TRANSFER CHARACTERISTICS							
Current Transfer Ratio	CTR	1000	-	15000	%	IF=1mA, VCE=2V	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	-	-	1.2	V	IF=20mA, IC=100mA	
Isolation Resistance	R_{ISO}	10^12	10^14	-	Ω	DC500V, 40 ~ 60% R.H.	
Floating Capacitance	C_{IO}	-	0.6	1	pF	V=0, f=1MHz	
Cut-off Frequency	fc	-	6	-	kHz	VCE=2V, IC=2mA RL=100Ω,-3dB	3
Response Time (Rise)	tr	-	91.5	300	μs	VCE=2V, IC=20mA RL=100Ω	4
Response Time (Fall)	tf	-	21.4	100	μs		4

Note 3. Fig.12&13

Note 4. Fig.14

CHARACTERISTIC CURVES

Fig.1 Forward Current vs. Ambient Temperature

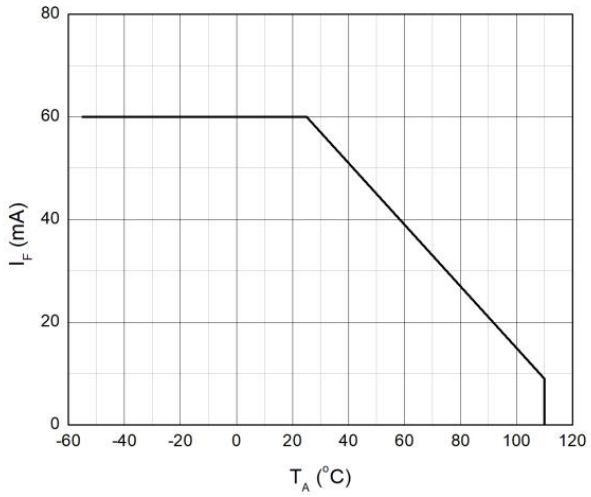


Fig.2 Collector Power Dissipation vs. Ambient Temperature

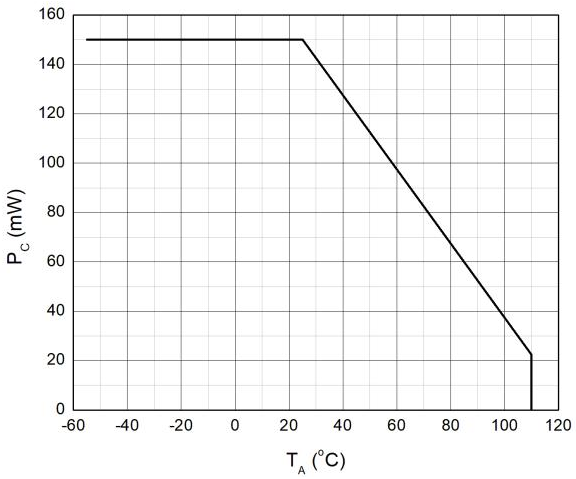


Fig.3 Forward Current vs. Forward Voltage

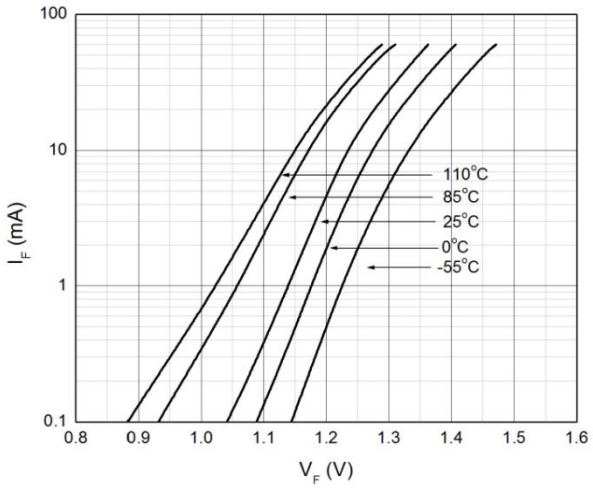


Fig.4 Collector Dark Current vs. Ambient Temperature

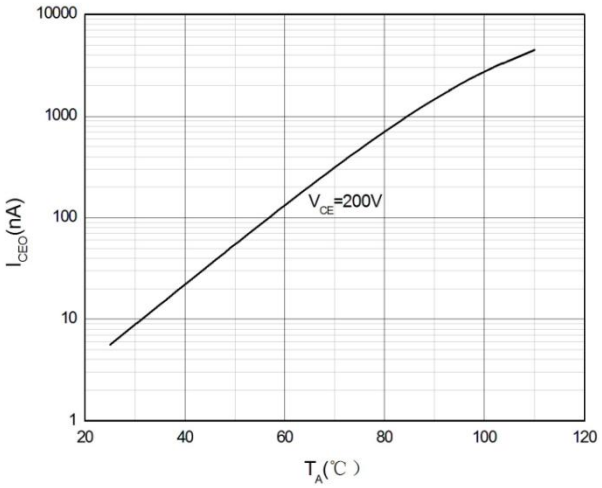
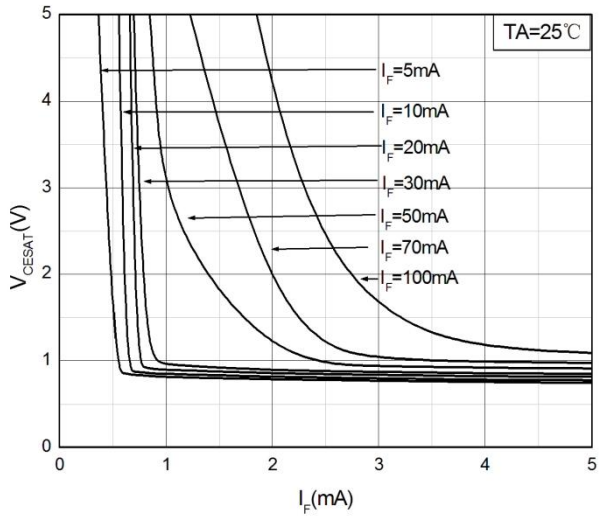
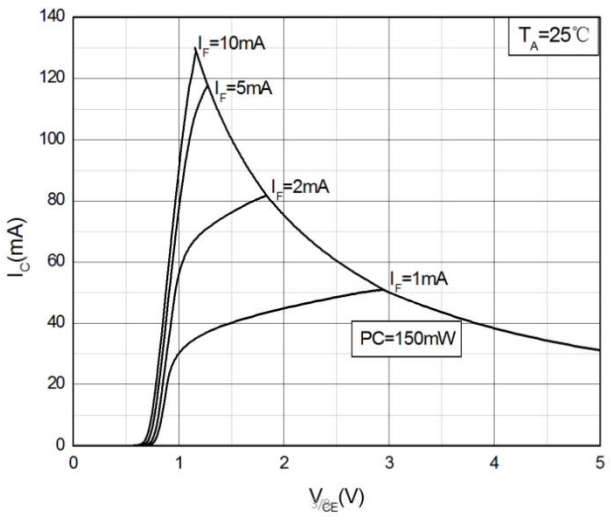


Fig.5 Collector-emitter Saturation Voltage vs. Forward Current

Fig.6 Collector Current vs. Collector-emitter Voltage

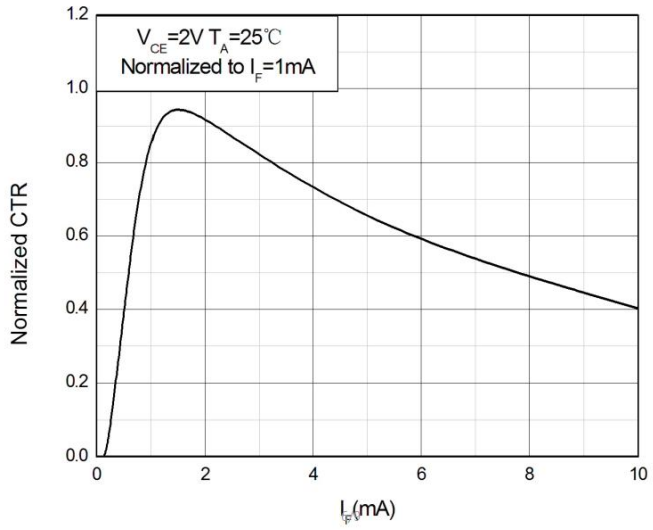




CHARACTERISTIC CURVES

Fig.7 Normalized Current Transfer Ratio vs. Forward Current

Fig.8 Normalized Current Transfer Ratio vs. Ambient Temperature



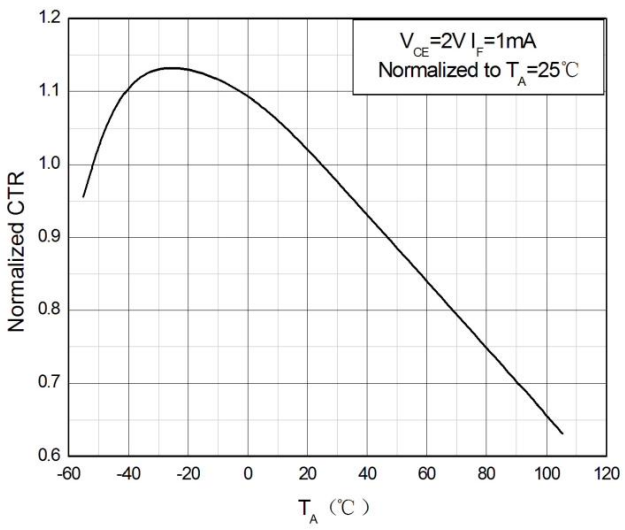
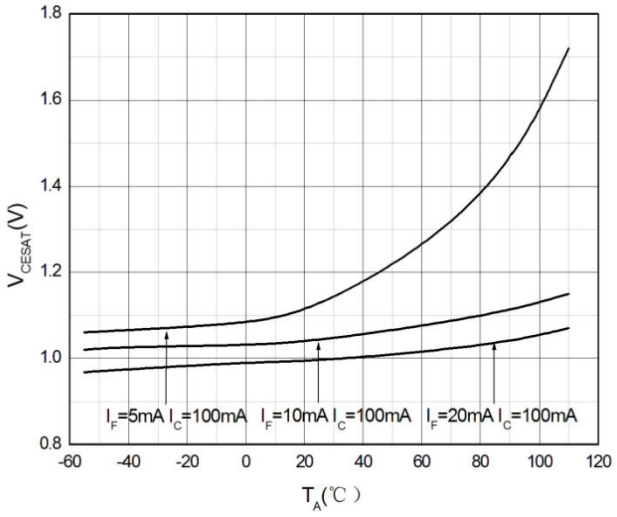


Fig.9 Collector-emitter Saturation Voltage vs. Ambient Temperature

Fig.10 Switching Time vs. Load Resistance



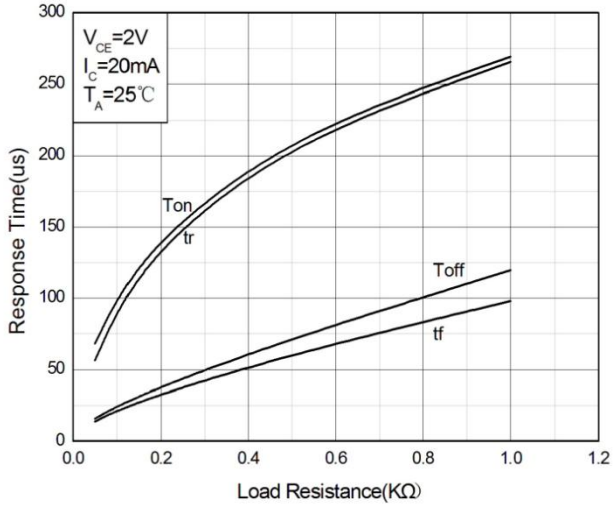
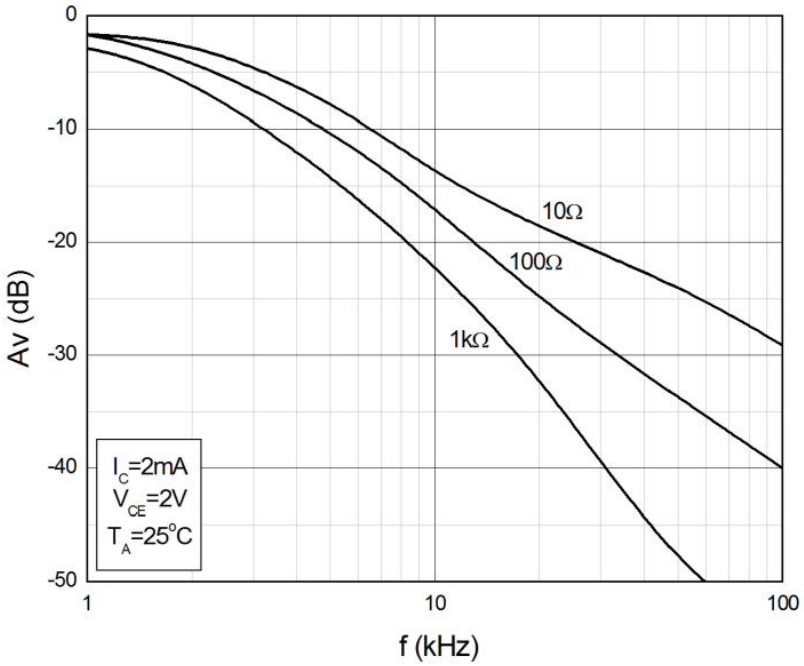


Fig.11 Frequency Response



TEST CIRCUITS

Fig.12 Test Circuits of Response Time

Fig.13 Curves of Response Time

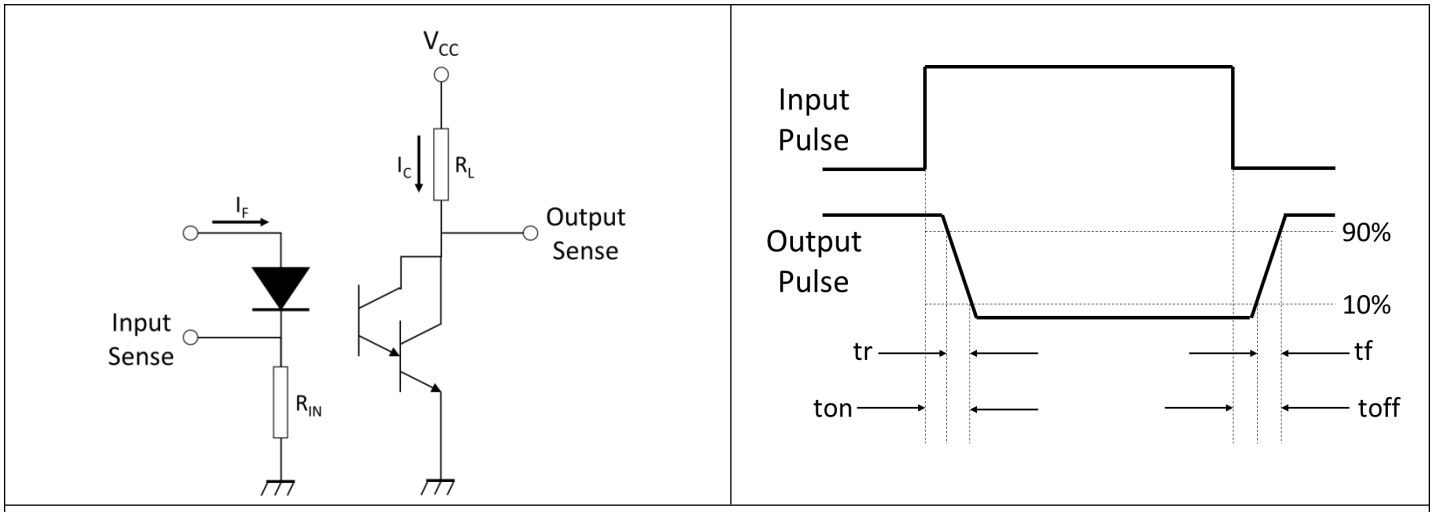
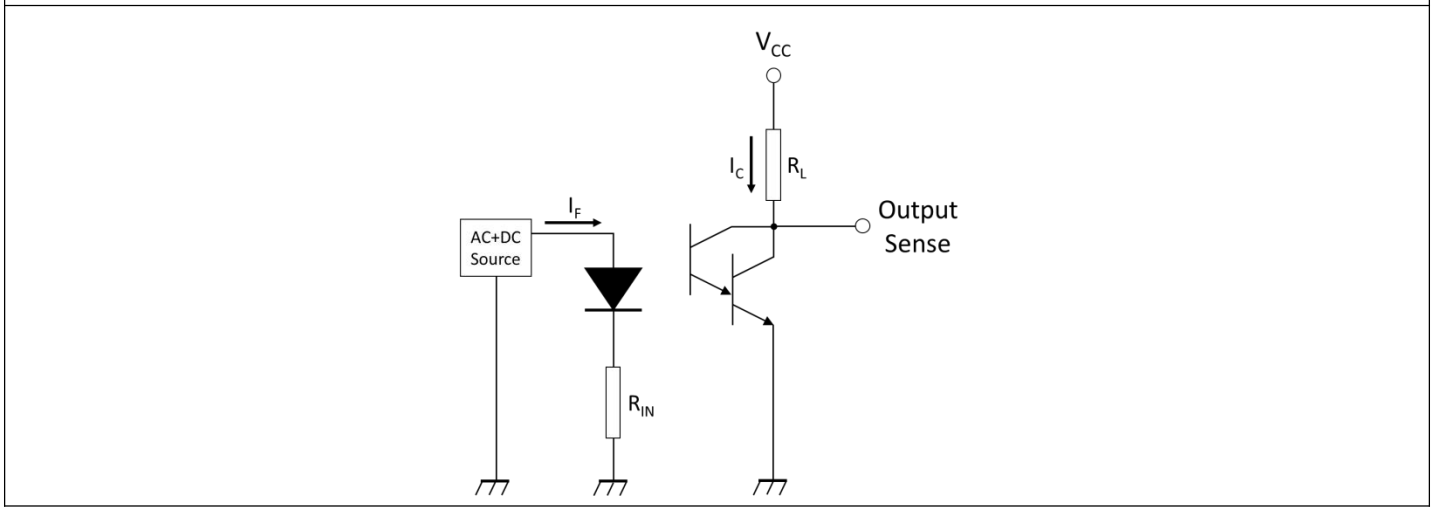
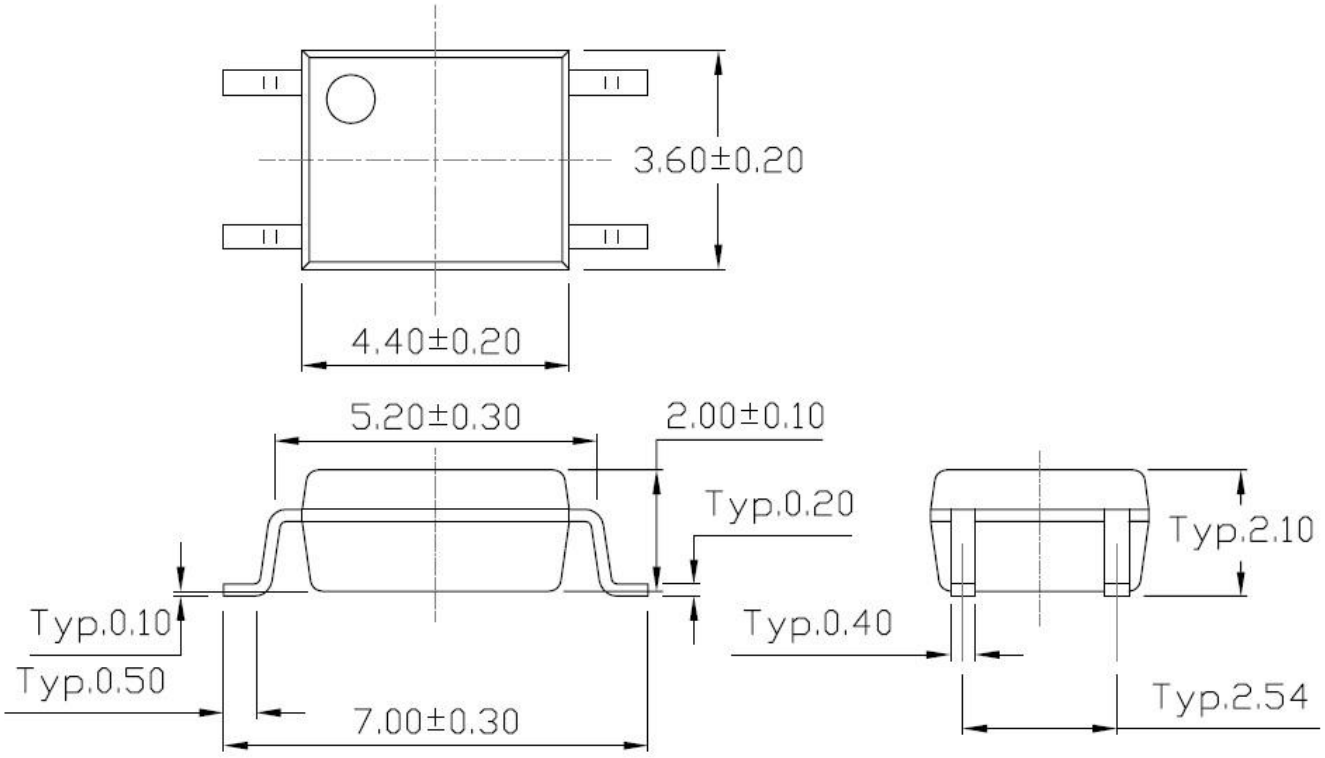


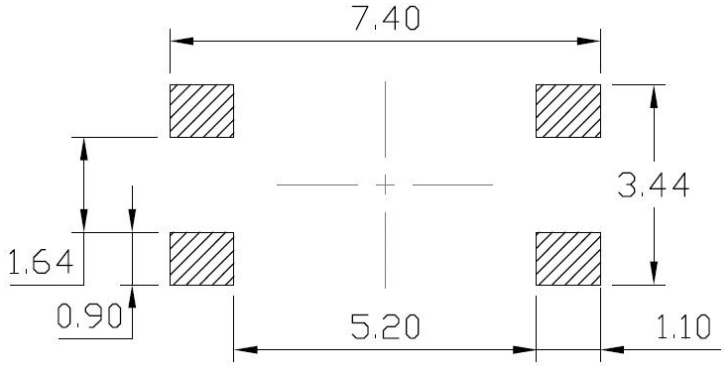
Fig.14 Test Circuits of Frequency Response



PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

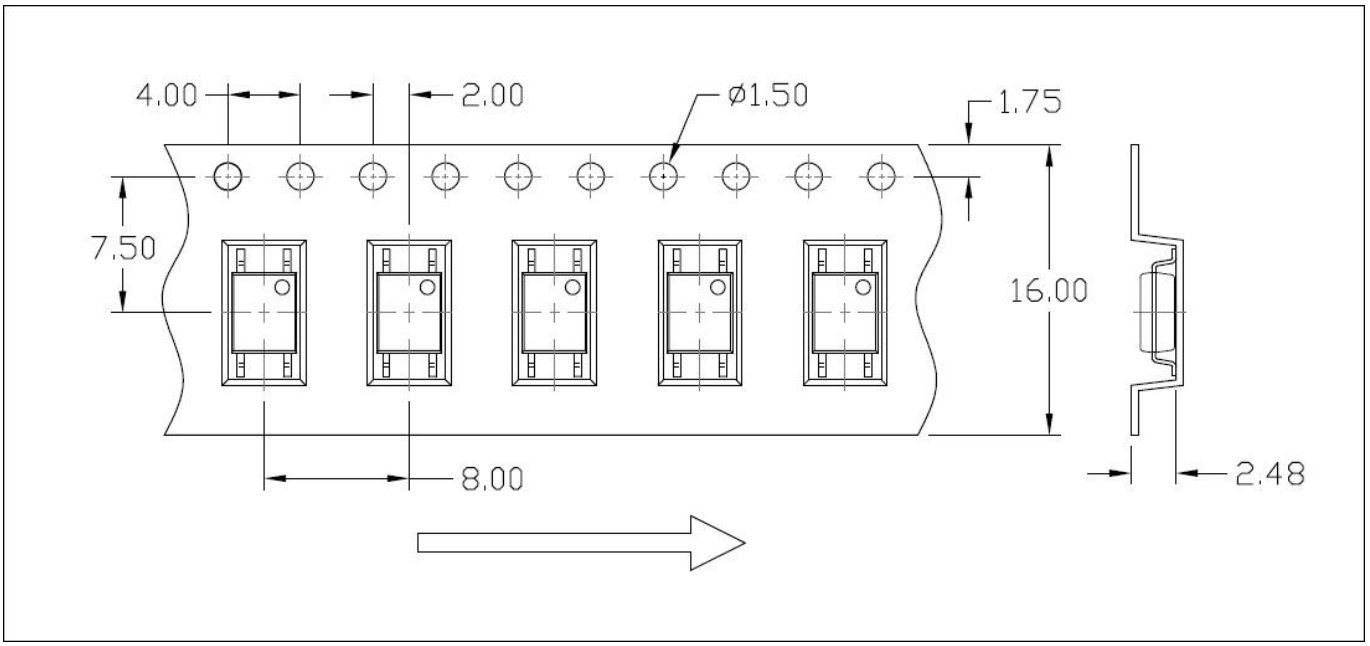


Recommended Solder Mask (Dimensions in mm unless otherwise stated)

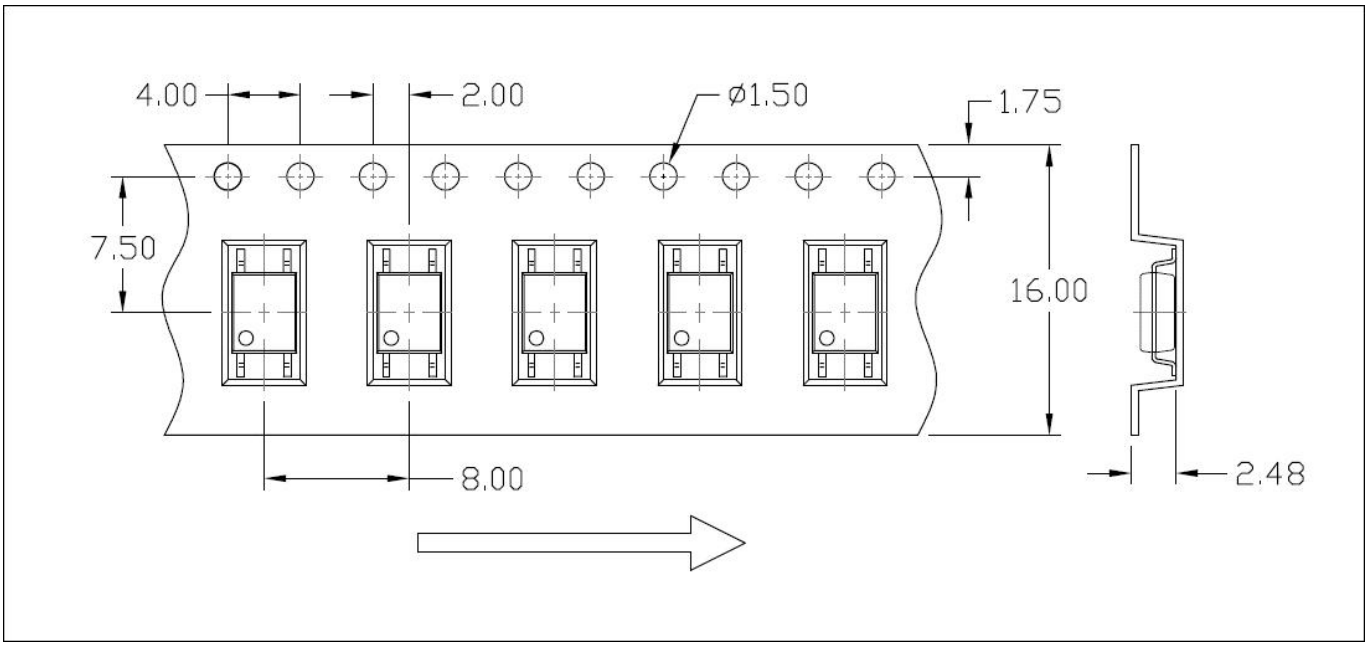


CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option T1

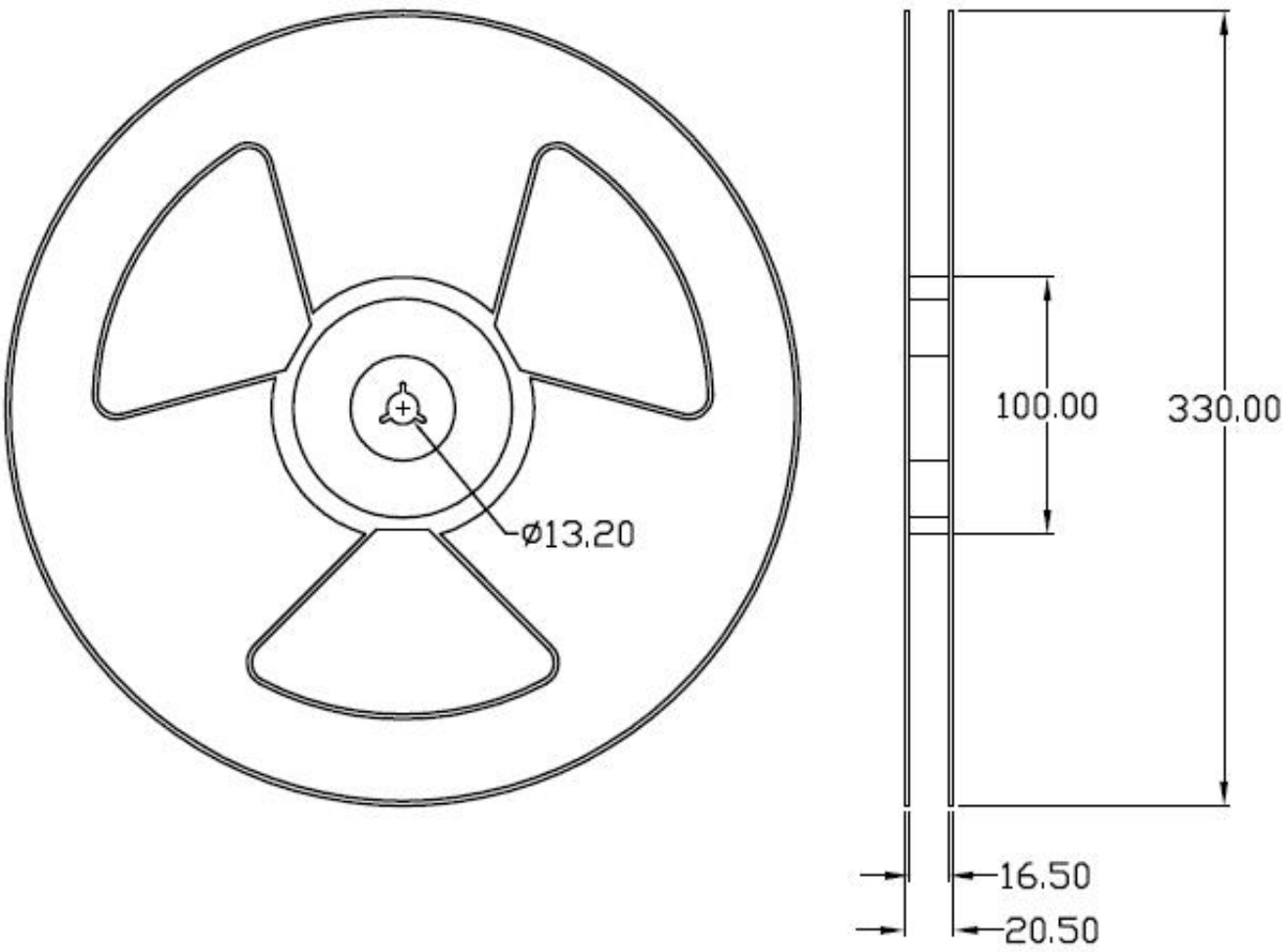


Option T2



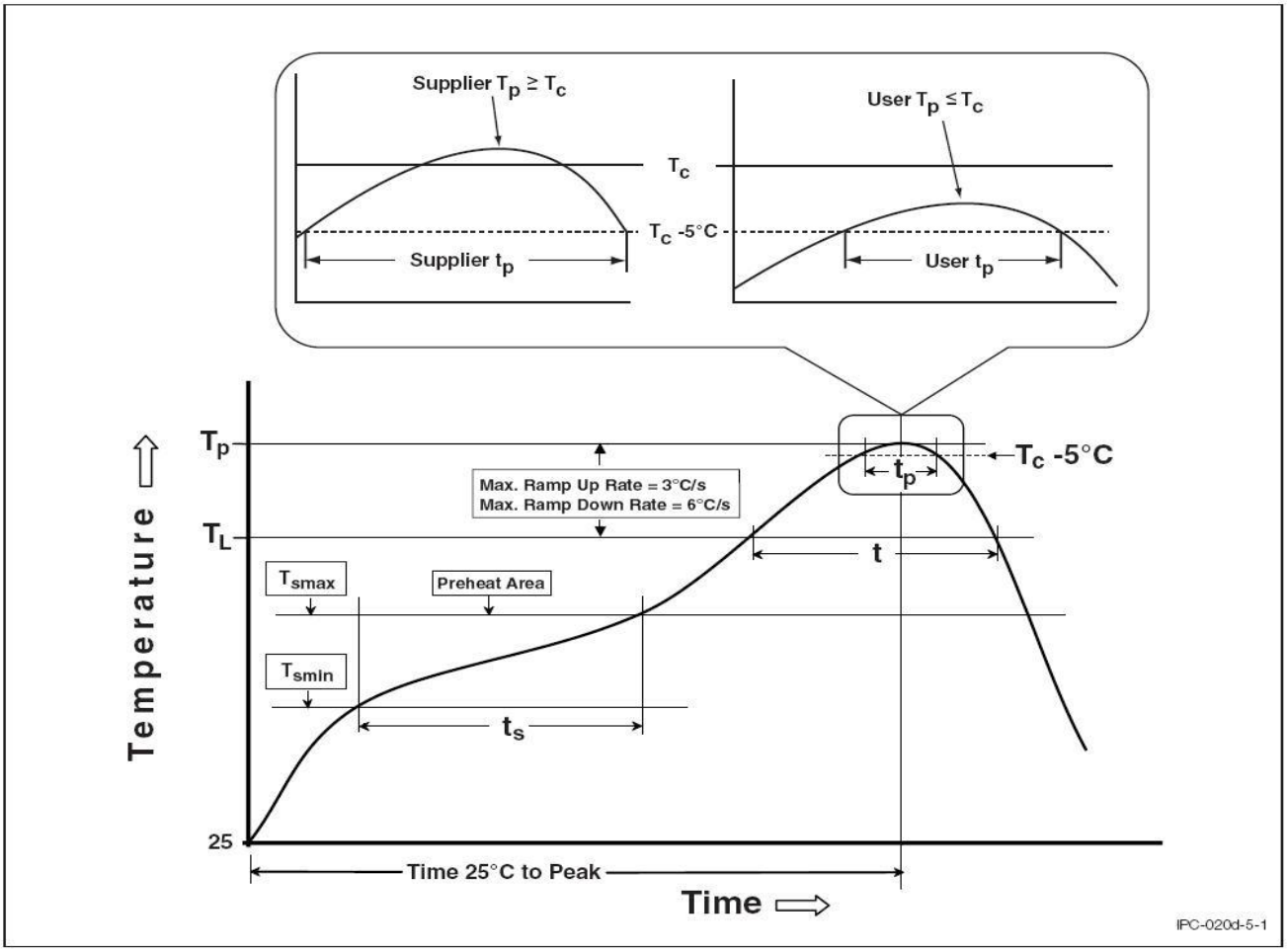
REEL SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option T1 & T2



REFLOW INFORMATION

REFLOW PROFILE



Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	100	150°C
Temperature Max. (Tsmax)	150	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds	60-120 seconds
Ramp-up Rate (tL to tP)	3°C/second max.	3°C/second max.
Liquidous Temperature (TL)	183°C	217°C
Time (tL) Maintained Above (TL)	60 – 150 seconds	60 – 150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time (tP) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (TP to TL)	6°C/second max	6°C/second max
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.